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September 2014

# FPF2495
# IntelliMAX™ 28 V, Over-Voltage, Over-Current Protection Load Switch with Adjustable Current-Limit Control

## Features

- $V_{IN}$: 2.5 V~5.5 V
- 28 V Absolute Ratings at $V_{OUT}$
- Current Capability: 2 A
- Adjustable Current Limit: 0.05 A ~ 2 A (Typ.)
  - 0.1 A~2 A with 10% Accuracy
  - < 0.1A with 15% Accuracy
- $R_{ON}$: Maximum 100 mΩ at 5 $V_{IN}$ and 1 A $I_{OUT}$
- Output OVP: Min.=5.6 V, Typ.=5.8 V, Max.=6 V
- No Output Discharge During Off State
- Open-Drain OCP on FLAGB
- Thermal Shutdown
- Under-Voltage Lockout (UVLO)
- True Reverse-Current Blocking (TRCB)
- Logic CMOS IO Meets JESD76 Standard for GPIO Interface and Related Power Supply Requirements
- ESD Protected:
  - Human Body Model: >2 kV
  - Charged Device Model: >2.5 kV
  - IEC 61000-4-2 Air Discharge: >15 kV
  - IEC 61000-4-2 Contact Discharge: >8 kV

## Applications

- Smart Phones, Tablet PCs
- Storage, DSLR, and Portable Devices

## Description

The FPF2495 advanced load-management switch targets applications requiring a highly integrated solution. It disconnects loads powered from the DC power rail (<6 V) with stringent off-state current targets and high load capacitances (<100 µF). The FPF2495 consists of a slew-rate controlled low-impedance MOSFET switch (100 mΩ maximum) and integrated analog features. The slew-rate controlled turn-on characteristic prevents inrush current and the resulting excessive voltage droop on power rails. FPF2495 has over-voltage protection and over-temperature protection.

The FPF2495 has a True Reverse-Current Blocking (TRCB) function that obstructs unwanted reverse current from $V_{OUT}$ to $V_{IN}$ during ON and OFF states. The exceptionally low off-state current drain (<2 µA maximum) facilitates compliance with standby power requirements. The input voltage range operates from 2.5 V to 5.5 $V_{DC}$ to support a wide range of applications in consumer, optical, medical, storage, portable, and industrial-device power management. Switch control is managed by a logic input (active HIGH) capable of interfacing directly with low-voltage control signal / General-Purpose Input / Output (GPIO) without an external pull-down resistor.

The device is packaged in advanced, fully “green” compliant, 1.21 mm x 1.21 mm, Wafer-Level Chip-Scale Package (WLCSP).

## Ordering Information

| Part Number | Operating Temperature Range | Package | Packing Method | Top Mark |
|---|---|---|---|---|
| FPF2495UCX | -40 to 85°C | 1.21 mm x 1.21 mm, Wafer-Level Chip-Scale Package (WLCSP) | Tape & Reel | TH |

## Application Diagram

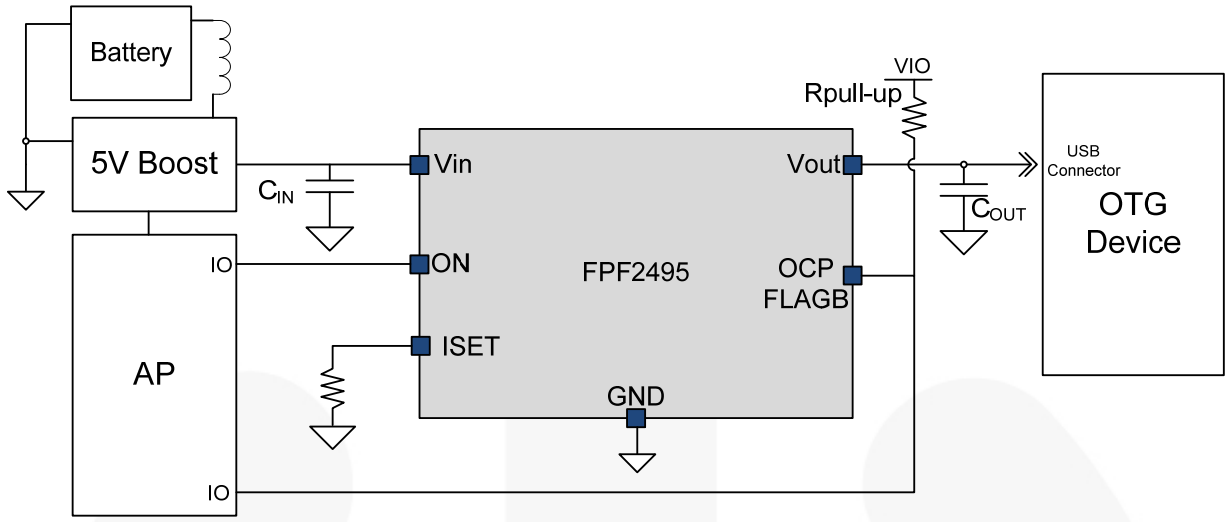



**Figure 1. Typical Application**

**Note:**

1. $C_{IN}$ and $C_{OUT}$ capacitors recommended for improvement of device stability.

## Functional Block Diagram

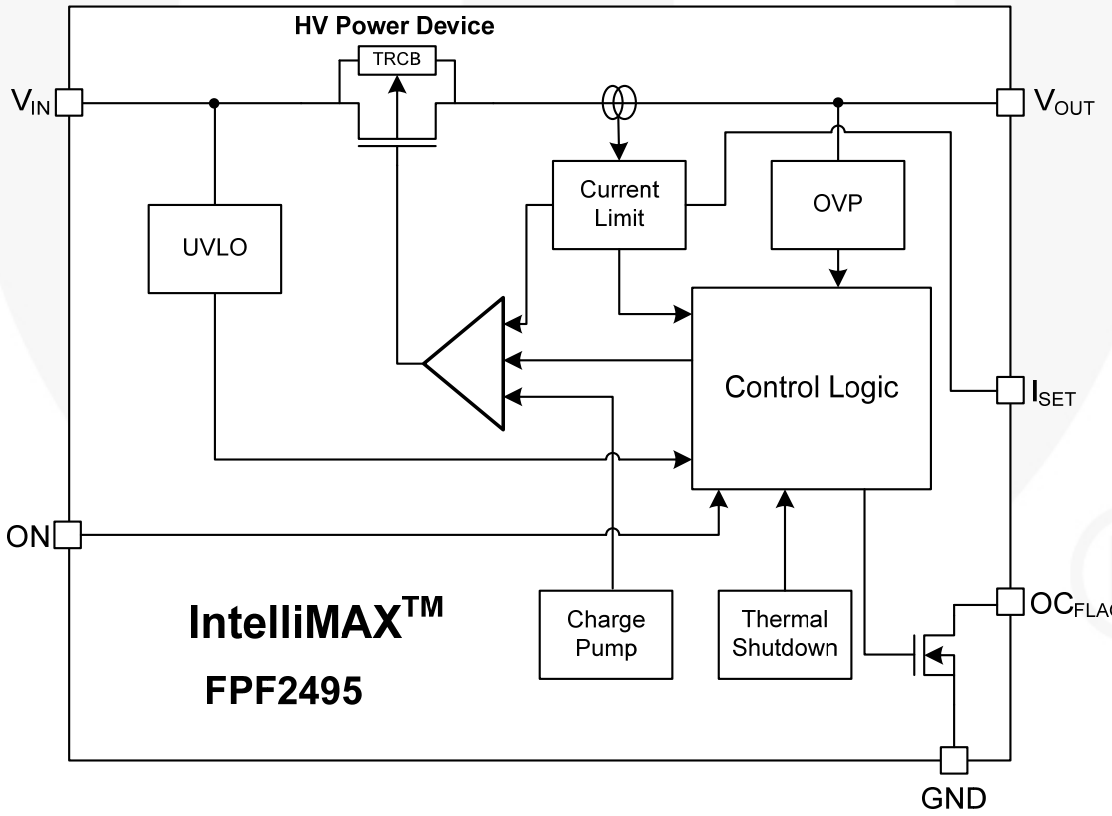



**Figure 2. Functional Block Diagram**

## Pin Configurations

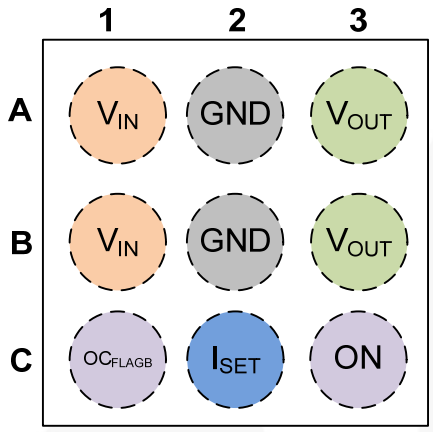



Figure 3. Pin Assignments (Top View)

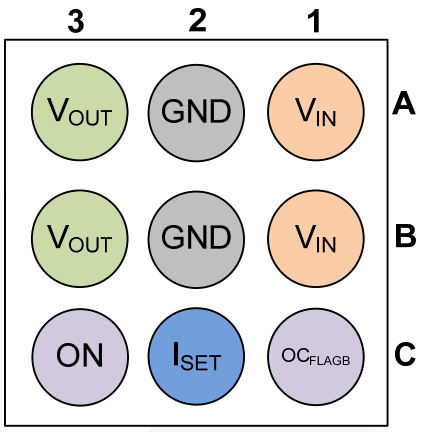



Figure 4. Pin Assignments (Bottom View)

## Pin Description

| Pin # | Name | Description | | |
|---|---|---|---|---|
| A3, B3 | $V_{OUT}$ | **Switch Output** | | |
| A1, B1 | $V_{IN}$ | **Supply Input**: Input to the power switch | | |
| A2 | GND | **Ground** (true device ground) | | |
| B2 | | | | |
| C3 | ON | **ON/OFF Control Input**: Active HIGH - GPIO compatible | **Logic HIGH** | Switch Enable |
| | | | **Logic LOW** | Switch Disable |
| C1 | $OC_{FLAGB}$ | **Fault Output**: Active LOW, open-drain output that indicates an input over current. External pull-up resistor to $V_{CC}$ is required. | | |
| C2 | $I_{SET}$ | **Current Limit Set Input**: A resistor from ISET to ground sets the current limit for the switch. | | |

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameters | | Min. | Max. | Unit |
|---|---|---|---|---|---|
| $V_{PIN}$ | $V_{OUT}$ to GND, $V_{OUT}$ to $V_{IN}$ | | -0.3 | 28.0 | V |
| | ON, $V_{IN}$, FLAGB, $I_{SET}$ to GND | | -0.3 | 6.0 | |
| $I_{SW}$ | Maximum Continuous Switch Current[4] | | | 2.2 | A |
| $t_{PD}$ | Total Power Dissipation at $T_A$=25°C | | | 1.0 | W |
| $T_J$ | Operating Junction Temperature | | -40 | +150 | °C |
| $T_{STG}$ | Storage Junction Temperature | | -65 | +150 | °C |
| $\Theta_{JA}$ | Thermal Resistance, Junction-to-Ambient (1-inch Square Pad of 2 oz. Copper) | | | 95[2] | °C/W |
| | | | | 110[3] | |
| ESD | Electrostatic Discharge Capability | Human Body Model, JESD22-A114 | 2.0 | | kV |
| | | Charged Device Model, JESD22-C101 | 2.5 | | |
| | IEC61000-4-2 System Level | Air Discharge ($V_{IN}$, $V_{ON}$, $V_{OUT}$ to GND) | 15.0 | | |
| | | Contact Discharge ($V_{IN}$, $V_{ON}$, $V_{OUT}$ to GND) | 8.0 | | |

**Notes:**

2. Measured using 2S2P JEDEC std. PCB.
3. Measured using 2S2P JEDEC PCB cold plate method.
4. Maximum Junction Temperature = 85°C.

## Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

| Symbol | Parameters | Min. | Max. | Unit |
|---|---|---|---|---|
| $V_{IN}$ | Supply Voltage | 2.5 | 5.5 | V |
| $T_A$ | Ambient Operating Temperature | -40 | 85 | °C |

## Electrical Characteristics

Unless otherwise noted; $V_{IN}$=2.5 to 5.5 V, $T_A$=-40 to +85°C; typical values are at $V_{IN}$=5 V and $T_A$=25°C.

| Symbol | Parameters | Condition | Min. | Typ. | Max. | Unit |
|---|---|---|---|---|---|---|
| **Basic Operation** | | | | | | |
| $V_{IN}$ | Input Voltage | | 2.5 | | 5.5 | V |
| $I_{Q(OFF)}$ | Off Supply Current | $V_{ON}$=GND, $V_{OUT}$=Open | | 1 | 2 | µA |
| $I_{SD(OFF)}$ | Shutdown Current | $V_{IN}$=5.5 V, $V_{OUT}$=0 V, $V_{ON}$=GND | | 0.1 | 4.0 | µA |
| $I_Q$ | Quiescent Current | $I_{OUT}$=0 mA | | 65 | 100 | µA |
| $R_{ON}$ | On Resistance | $V_{IN}$=5.0 V, $I_{OUT}$=1 A | | 70 | 100 | mΩ |
| | | $V_{IN}$=3.7 V, $I_{OUT}$=1 A | | 75 | 105 | |
| $R_{ON}$ | On Resistance[6] | $V_{IN}$=5.0 V, $I_{OUT}$=1.5 A | | 70 | | mΩ |
| $V_{IH}$ | ON Input Logic HIGH Voltage | $V_{IN}$=2.5 V to 5.5 V | 1.15 | | | V |
| $V_{IL}$ | ON Input Logic LOW Voltage | $V_{IN}$=2.5 V to 5.5 V | | | 0.65 | V |
| $V_{IL\_FLAG}$ | FLAGB Output Logic LOW Voltage | $V_{IN}$=5 V, $I_{SINK}$=10 mA | | 0.1 | 0.2 | V |
| | | $V_{IN}$=2.5 V, $I_{SINK}$=10 mA | | 0.15 | 0.30 | |
| $I_{FLAGB\_LK}$ | FLAGB Output HIGH Leakage Current | $V_{IN}$=5 V, Switch On | | | 1 | µA |
| $I_{ON}$ | On Input Leakage | $V_{ON}$=0 V to $V_{IN}$ | | | 1.0 | µA |
| $R_{ON\_PD}$ | Pull-Down Resistance at ON Pin | $V_{IN}$=2.5~5.5 V, $V_{ON}$=HIGH, $T_A$=-40 to 85°C | | 14 | | MΩ |
| **Over-Voltage Protection** | | | | | | |
| $V_{OV\_TRIP}$ | Output OVP Lockout | $V_{OUT}$ Rising Threshold | 5.50 | 5.80 | 6.00 | V |
| | | $V_{OUT}$ Falling Threshold | | 5.50 | | |
| $OUT_{HYS}$ | Output OVP Hysteresis | $V_{OUT}$ Falling Threshold | | 0.3 | | V |
| $t_{OVP}$ | OVP Response Time[6] | $I_{OUT}$=0.5 A, $C_L$=1 µF, $T_A$=25°C, $V_{OUT}$ from 5.5 V to 6.0 V | 1 | | 4[6] | µs |
| **Over-Current Protection** | | | | | | |
| $I_{LIM}$ | Current Limit | $V_{IN}$=5 V, $R_{SET}$=20000 Ω, $V_{OUT}$=1.68 to 5 V with 15% Accuracy[5] | 42 | 50 | 58 | mA |
| | | $V_{IN}$=5 V, $R_{SET}$=2100 Ω, $V_{OUT}$=1.68 to 5 V with 10% Accuracy[5] | 450 | 500 | 550 | |
| | | $V_{IN}$=5 V, $R_{SET}$=1070 Ω, $V_{OUT}$=1.68 to 5 V with 10% Accuracy[5] | 900 | 1000 | 1100 | |
| $V_{UVLO}$ | Under-Voltage Lockout | $V_{IN}$ Increasing | | 2.4 | | V |
| | | $V_{IN}$ Decreasing | | 2.2 | | |
| $V_{UVLO\_HYS}$ | UVLO Hysteresis | | | 200 | | mV |
| $V_{T\_RCB}$ | RCB Protection Trip Point | $V_{OUT}$ - $V_{IN}$ | | 50 | | mV |
| $V_{R\_RCB}$ | RCB Protection Release Trip Point | $V_{IN}$ - $V_{OUT}$ | | 50 | | mV |

*Continued on the following page…*

## Electrical Characteristics (Continued)

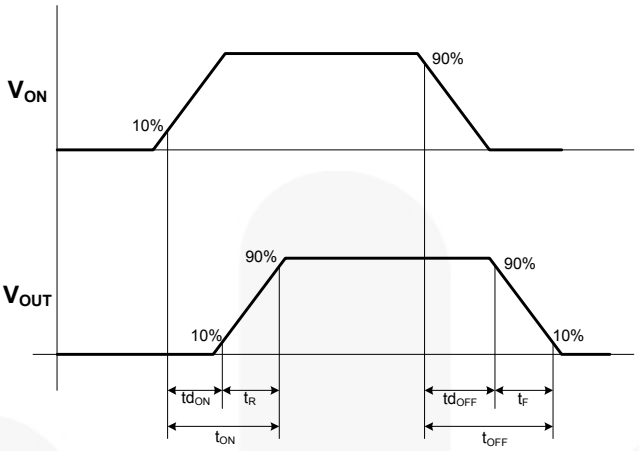
Unless otherwise noted; $V_{IN}$=2.5 to 5.5 V, $T_A$=-40 to +85°C; typical values are at $V_{IN}$=5 V and $T_A$=25°C.

| Symbol | Parameters | Conditions | Min. | Typ. | Max. | Unit |
|---|---|---|---|---|---|---|
| $V_{RCB\_HYS}$ | RCB Hysteresis | | | 100 | | mV |
| $t_{RCB}$ | Default RCB Response Time | $V_{IN}$=5 V, $V_{ON}$=High/Low | | 2 | | µs |
| $I_{RCB}$ | RCB Current | $V_{ON}$=0 V, $V_{OUT}$=5.5 V, | | 7 | | µA |
| $t_{HOCP}$ | Hard Over-Current Response Time | Moderate Over-Current Condition, $I_{OUT} \geq I_{LIM}$, $V_{OUT}$=0 V | | 6 | | µs |
| $t_{OCP}$ | Over-Current Response Time | Moderate Over-Current Condition, $I_{OUT} \geq I_{LIM}$ $V_{OUT} \leq V_{IN}$ | | 7 | | µs |
| $t_{OC\_FLAG}$ | Over-Current Flag Response Time | When Over-Current Occurs to Flag Pulling LOW | | 8 | | ms |
| TSD | Thermal Shutdown | Shutdown Threshold | | 150 | | °C |
| | | Return from Shutdown | | 130 | | |
| | | Hysteresis | | 20 | | |
| **Dynamic Characteristics** | | | | | | |
| $t_{DON}$ | Turn-On Delay(6,7) | $V_{IN}$=5 V, $R_L$=100 Ω, $C_L$=1 µF, $T_A$=25°C, $R_{SET}$=2040 Ω | | 0.67 | | ms |
| $t_R$ | $V_{OUT}$ Rise Time(6,7) | | | 0.69 | | ms |
| $t_{ON}$ | Turn-On Time(6,8) | | | 1.36 | | ms |
| $t_{DOFF}$ | Turn-Off Delay(7,6) | | | 0.01 | | ms |
| $t_F$ | $V_{OUT}$ Fall Time(7,6) | | | 0.22 | | ms |
| $t_{OFF}$ | Turn-Off Time(9,6) | | | 0.23 | | ms |
| $t_{DON}$ | Turn-On Delay(7,10) | $V_{IN}$=5 V, $R_L$=3.8 Ω, $C_L$=10 µF, $T_A$=-40 to 85°C, $R_{SET}$=634 Ω | | 0.65 | 0.78 | ms |
| $t_R$ | $V_{OUT}$ Rise Time(7,10) | | | 0.65 | 0.82 | ms |
| $t_{ON}$ | Turn-On Time(8,10) | | | 1.3 | 1.6 | ms |
| $t_{DOFF}$ | Turn-Off Delay(7,10) | | | 4 | 10 | µs |
| $t_F$ | $V_{OUT}$ Fall Time(7,10) | | | 76 | 120 | µs |
| $t_{OFF}$ | Turn-Off Time(9,10) | | | 80 | 130 | µs |

**Notes:**

5. Characterization based on 1% tolerance resistor.
6. This parameter is guaranteed by design and characterization; not production tested.
7. $t_{DON}/t_{DOFF}/t_R/t_F$ are defined in Figure 5 below.
8. $t_{ON}=t_R + t_{DON}$.
9. $t_{OFF}=t_F + t_{DOFF}$.
10. This parameter is guaranteed by design.

## Timing Diagram




**where:**

$t_{DON}$ = Delay On Time
$t_R$ = $V_{OUT}$ Rise Time
$t_{ON}$ = Turn-On Time
$t_{DOFF}$ = Delay Off Time
$t_F$ = $V_{OUT}$ Fall Time
$t_{OFF}$ = Turn Off Time

**Figure 5. Timing Diagram**

## Operation and Application Description

### Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into discharge load capacitor; a capacitor must be placed in between the $V_{IN}$ and GND pins. A high-value capacitor on $C_{IN}$ can be used to reduce the voltage drop in high-current applications.

### Output Capacitor

An output capacitor should be placed between the $V_{OUT}$ and GND pins. This capacitor prevents parasitic board inductance from forcing $V_{OUT}$ below GND when the switch is on. This capacitor also prevents reverse inrush current from creating a voltage spike that could damage the device in the case of a $V_{OUT}$ short.

### Fault Reporting

Upon the detection of an over-current, OC_FLAGB signal the fault by activating LOW.

### Current Limiting

The current limit ensures that the current through the switch does not exceed the maximum set value, while not limiting the minimum value. The current at which the part's limit is adjustable through the selection of the external resistor connected to the ISET pin. Information for selecting the resistor is found in the section below. The device acts as a constant-current source when the load draws more than the maximum value set by the device until thermal shutdown occurs. The device recovers if the die temperature drops below the threshold temperature.

### Under-Voltage Lockout (UVLO)

The under-voltage lockout turns the switch off if the input voltage drops below the lockout threshold. With the ON pin active, the input voltage rising above the UVLO threshold releases the lockout and enables the switch.

### True Reverse-Current Blocking

The true reverse-current blocking feature protects the input source against current flow from output to input regardless of whether the load switch is on or off.

### Thermal Shutdown

The thermal shutdown protects the die from internally or externally generated excessive temperature. During an over-temperature condition, the switch is turned off. The switch automatically turns on again if the temperature of the die drops below the threshold temperature.

## Setting Current Limit

The current limit is set with an external resistor connected between the $I_{SET}$ and GND pins. The resistor is selected using Table 1. Resistor tolerance of 1% or less is recommended.

**Table 1. Current Limit Settings by $R_{SET}$[11]**

| $R_{SET}\Omega$ | Min. Current Limit (mA) | Typ. Current Limit (mA) | Max. Current Limit (mA) |
|---|---|---|---|
| 528 | 1800 | 2000 | 2200 |
| 604 | 1570 | 1750 | 1920 |
| 680 | 1350 | 1500 | 1650 |
| 866 | 1125 | 1250 | 1375 |
| 1070 | 900 | 1000 | 1100 |
| 1200 | 810 | 900 | 990 |
| 1330 | 720 | 800 | 880 |
| 1500 | 630 | 700 | 770 |
| 1740 | 540 | 600 | 660 |
| 2100 | 450 | 500 | 550 |
| 2320 | 405 | 450 | 495 |
| 2550 | 360 | 400 | 440 |
| 2940 | 315 | 350 | 385 |
| 3400 | 370 | 300 | 330 |
| 4020 | 225 | 250 | 275 |
| 4990 | 180 | 200 | 220 |
| 6490 | 135 | 150 | 165 |
| 9530 | 90 | 100 | 110 |
| 20000 | 42 | 50 | 58 |

**Note:**

11. Table values based on 1% tolerance resistor.
12. For 50 mA setting, tolerance is ±15% with 1%.

## Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance may have on normal and short-circuit operation. Using wide traces for VIN, VOUT, GND helps minimize parasitic electrical effects along with minimizing the case-to-ambient thermal impedance.

## Typical Performance Characteristics

$T_A$=25°C.


**Figure 6. $t_{ON}$ Response**


**Figure 7. OVP Response (Increase $V_{OUT}$ to OVP Trip Point)**


**Figure 8. OC_FLAGB Response Time (Toggle $R_{LOAD}$ from High to Low Resistance)**

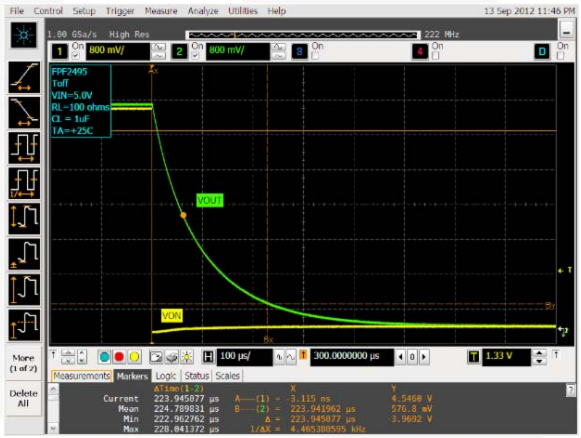


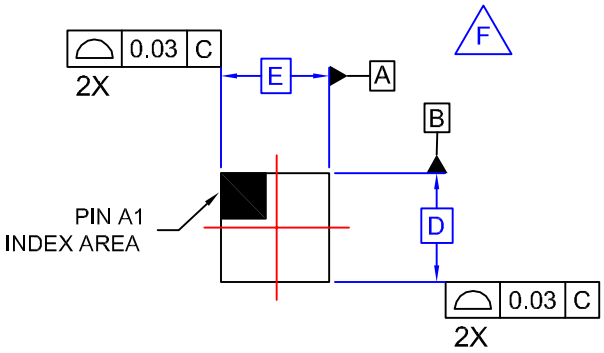

**Figure 9. $t_{OFF}$ Response**


**Figure 10. $t_{OCP}$ Response Time**

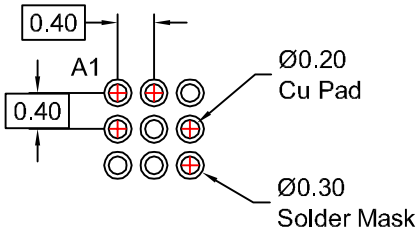
## Product-Specific Dimensions

| D | E | X | Y |
|---|---|---|---|
| 1210 µm ±30 µm | 1210 µm ±30 µm | 205 µm | 205 µm |

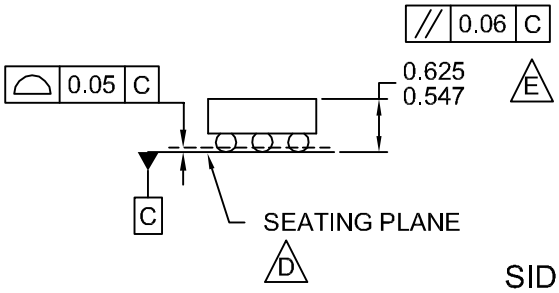
| REVISIONS | | | |
|---|---|---|---|
| REV | DESCRIPTION | DATE | BY/SITE |
| 1 | INITIAL DRAWING RELEASE. | 2-15-2008 | L. ENGLAND/FSME |
| 2 | Updated land pattern to individual solder mask openings.<br>Removed solder alloy note. Other misc updates for standardization. | 4-9-2010 | L. ENGLAND/FSME |

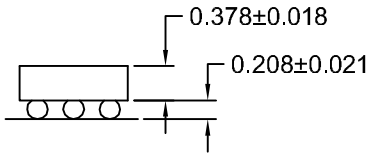



TOP VIEW

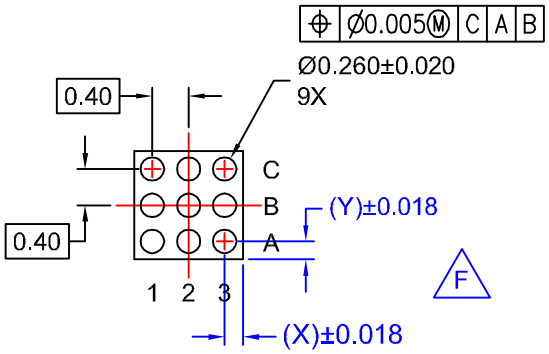



LAND PATTERN RECOMMENDATION
(NSMD PAD TYPE)




SIDE VIEWS




BOTTOM VIEW

## NOTES:

A. NO JEDEC REGISTRATION APPLIES.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS AND TOLERANCE PER ASMEY14.5M, 1994.

D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.

E. PACKAGE NOMINAL HEIGHT IS 586 MICRONS ±39 MICRONS (547-625 MICRONS).

F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

G. DRAWING FILNAME: MKT-UC009ABrev2

| APPROVALS | DATE |
|---|---|
| DRAWN L. England | 4-9-10 |
| DFTG. CHK. H. Allen | 4-9-10 |
| ENGR. CHK. | |
| | |

FAIRCHILD SEMICONDUCTOR™

9 BALL WLCSP, 3X3 ARRAY
0.4MM PITCH, 250UM BALL

PROJECTION
INCH
[MM]

| SCALE | SIZE | DRAWING NUMBER | REV |
|---|---|---|---|
| N/A | N/A | MKT-UC009AB | 2 |

DO NOT SCALE DRAWING | SHEET 1 of 1

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